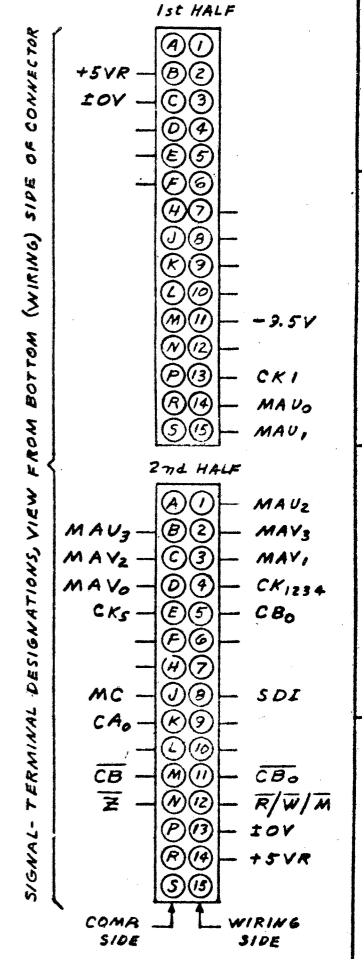
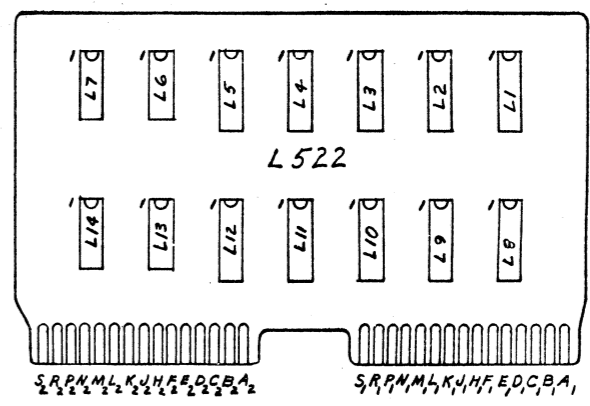
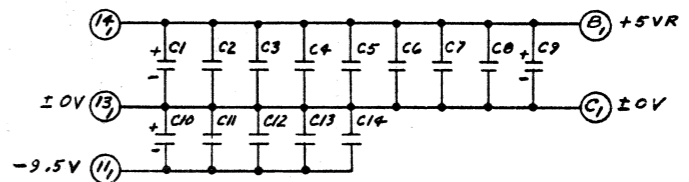


LOCATION	TYPE	WANG PART No.	TERM. No. $V_{CC} +5V$	TERM. No. $\pm 0V$	QTY
L1, 2, 3, 4, 8, 9, 10, 11	1101A	376-0000	5	14	8
L5, 12	5N7495N	376-0013	5	12	2
L6, 13	5N7495N	376-0059	14	7	2
L7	5N7404N	376-0010	14	7	1

COMP.	SIZE/TYPER	WANG PART No.	QTY
C1, 9	10-4T 16VDC	300-3006	2
C2, 3, 4, 5, 6, 7, 8	.05-T	300-1900	7
C11, 12, 13, 14	.02-T	300-1904	4
C10	25-4T 16VDC	300-3008	1



WANG LABORATORIES INC. TEWKSBURY, MASS.			
MODEL NO. 1200	DRAWN 9/17/71	APP. 3/10/72	REV.
TITLE SCHEMATIC LOGIBLOC # L522 RAM (MOS MEMORY)		DWB. NO. 6152-1	
SHT. OF		REV.	

REVISION	
NO.	